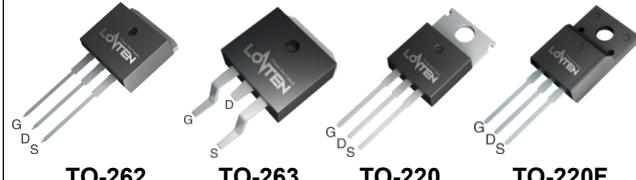
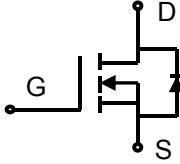


## Lonten N-channel 650V, 12A Power MOSFET

Description	Product Summary
The Power MOSFET is fabricated using the advanced planer VDMOS technology. The resulting device has low conduction resistance, superior switching performance and high avalanche energy.	<p><math>V_{DSS}</math> 650V  <math>I_D</math> 12A  <math>R_{DS(on),max}</math> 0.8Ω  <math>Q_{g,typ}</math> 41.9 nC</p>
<b>Features</b>	 <p>TO-262      TO-263      TO-220      TO-220F</p>
<b>Applications</b>	 <p>TO-220F Narrow Pin</p>
	 <p>N-Channel MOSFET</p>

### Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	650	V
Continuous drain current ( $T_c = 25^\circ\text{C}$ ) ( $T_c = 100^\circ\text{C}$ )	$I_D$	12 7.5	A A
Pulsed drain current <sup>1)</sup>	$I_{DM}$	48	A
Gate-Source voltage	$V_{GSS}$	$\pm 30$	V
Avalanche energy, single pulse <sup>2)</sup>	$E_{AS}$	500	mJ
Peak diode recovery dv/dt <sup>3)</sup>	dv/dt	5	V/ns
Power Dissipation TO-220F/TO-220F Narrow Pin ( $T_c = 25^\circ\text{C}$ ) Derate above 25°C	$P_D$	42 0.34	W W/°C
Power Dissipation TO-220\ TO-262\ TO-263 ( $T_c = 25^\circ\text{C}$ ) Derate above 25°C		150 1.2	W W/°C
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +150	°C
Continuous diode forward current	$I_S$	12	A
Diode pulse current	$I_{S,pulse}$	48	A

### Thermal Characteristics

Parameter	Symbol	Value		Unit
		TO-220F\TO-220F Narrow Pin	TO-220\TO-262\TO-263	
Thermal resistance, Junction-to-case	$R_{\theta JC}$	2.98	0.83	°C/W

Thermal resistance, Junction-to-ambient	$R_{\theta JA}$	110	62.5	$^{\circ}\text{C/W}$
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### Package Marking and Ordering Information

Device	Device Package	Marking	Units/Tube	Units/Reel
LNC12N65	TO-220	LNC12N65	50	
LND12N65	TO-220F	LND12N65	50	
LNE12N65	TO-263	LNE12N65		800
LNF12N65	TO-262	LNF12N65	50	
LNDN12N65	TO-220F Narrow Pin	LNDN12N65	50	

### Electrical Characteristics

$T_c = 25^{\circ}\text{C}$  unless otherwise noted

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
<b>Static characteristics</b>						
Drain-source breakdown voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0 \text{ V}, I_{\text{D}}=0.25 \text{ mA}$	650	-	-	V
Gate threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=0.25 \text{ mA}$	2	-	4	V
Drain cut-off current	$I_{\text{DSS}}$	$V_{\text{DS}}=650 \text{ V}, V_{\text{GS}}=0 \text{ V},$ $T_j = 25^{\circ}\text{C}$ $T_j = 125^{\circ}\text{C}$	-	-	1	$\mu\text{A}$
Gate leakage current, Forward	$I_{\text{GSSF}}$	$V_{\text{GS}}=30 \text{ V}, V_{\text{DS}}=0 \text{ V}$	-	-	100	nA
Gate leakage current, Reverse	$I_{\text{GSSR}}$	$V_{\text{GS}}=-30 \text{ V}, V_{\text{DS}}=0 \text{ V}$	-	-	-100	nA
Drain-source on-state resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=10 \text{ V}, I_{\text{D}}=6 \text{ A}$	-	0.64	0.8	$\Omega$
<b>Dynamic characteristics</b>						
Input capacitance	$C_{\text{iss}}$	$V_{\text{DS}} = 25 \text{ V}, V_{\text{GS}} = 0 \text{ V},$ $f = 1 \text{ MHz}$	-	2000	-	pF
Output capacitance	$C_{\text{oss}}$		-	164	-	
Reverse transfer capacitance	$C_{\text{rss}}$		-	7.4	-	
Turn-on delay time	$t_{\text{d(on)}}$	$V_{\text{DD}} = 325 \text{ V}, I_{\text{D}} = 12 \text{ A}$ $R_G = 10 \Omega, V_{\text{GS}}=15 \text{ V}$	-	14.6	-	ns
Rise time	$t_r$		-	37.8	-	
Turn-off delay time	$t_{\text{d(off)}}$		-	69.3	-	
Fall time	$t_f$		-	15.8	-	
<b>Gate charge characteristics</b>						
Gate to source charge	$Q_{\text{gs}}$	$V_{\text{DD}}=520 \text{ V}, I_{\text{D}}=12 \text{ A},$ $V_{\text{GS}}=0 \text{ to } 10 \text{ V}$	-	10.8	-	nC
Gate to drain charge	$Q_{\text{gd}}$		-	15	-	
Gate charge total	$Q_g$		-	41.9	-	
Gate plateau voltage	$V_{\text{plateau}}$		-	5	-	
<b>Reverse diode characteristics</b>						
Diode forward voltage	$V_{\text{SD}}$	$V_{\text{GS}}=0 \text{ V}, I_{\text{F}}=12 \text{ A}$	-	-	1.5	V
Reverse recovery time	$t_{\text{rr}}$	$V_R=325 \text{ V}, I_{\text{F}}=12 \text{ A},$ $dI_{\text{F}}/dt=100 \text{ A}/\mu\text{s}$	-	450.4	-	ns
Reverse recovery charge	$Q_{\text{rr}}$		-	4.75	-	$\mu\text{C}$
Peak reverse recovery current	$I_{\text{rm}}$		-	21.1	-	A

#### Notes:

1. Pulse width limited by maximum junction temperature.
2.  $L=10\text{mH}$ ,  $I_{AS} = 10\text{A}$ , Starting  $T_j= 25^{\circ}\text{C}$ .
3.  $I_{SD} = 12\text{A}$ ,  $di/dt \leq 100\text{A}/\mu\text{s}$ ,  $V_{DD} \leq \text{BV}_{\text{DS}}$ , Starting  $T_j= 25^{\circ}\text{C}$ .

## Electrical Characteristics Diagrams

Figure 1. Typical Output Characteristics

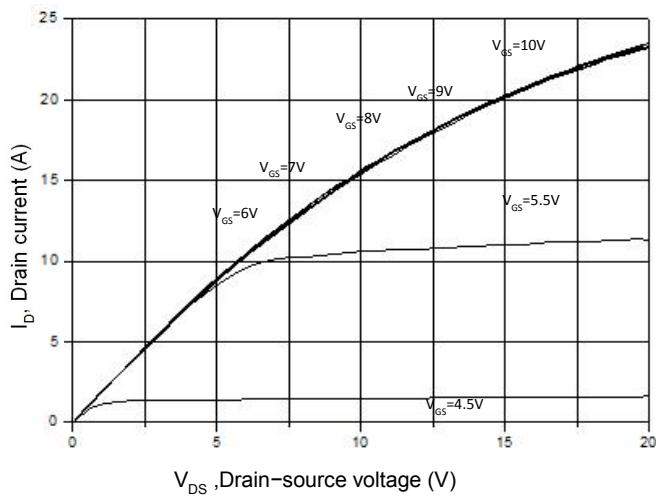


Figure 2. Transfer Characteristics

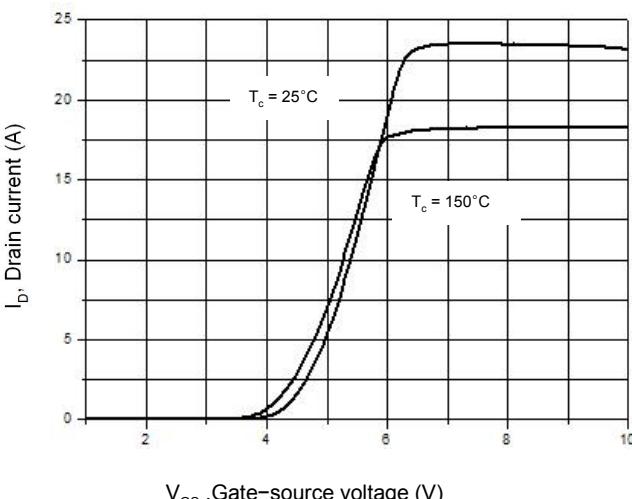


Figure 3. On-Resistance Variation vs. Drain Current

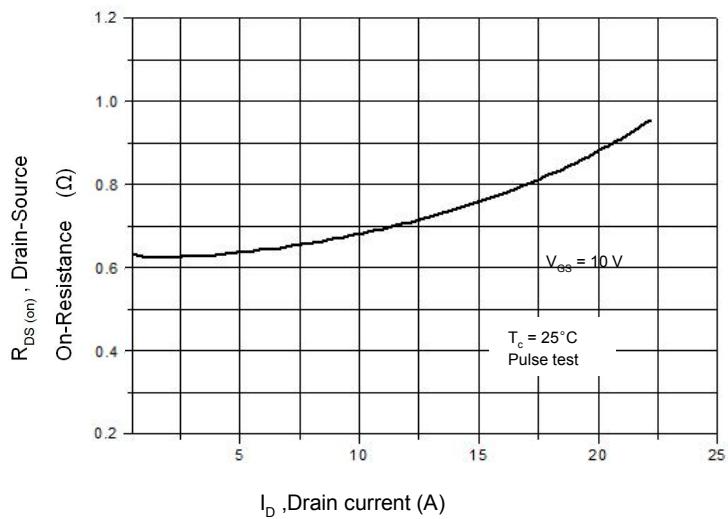


Figure 4. Threshold Voltage vs. Temperature

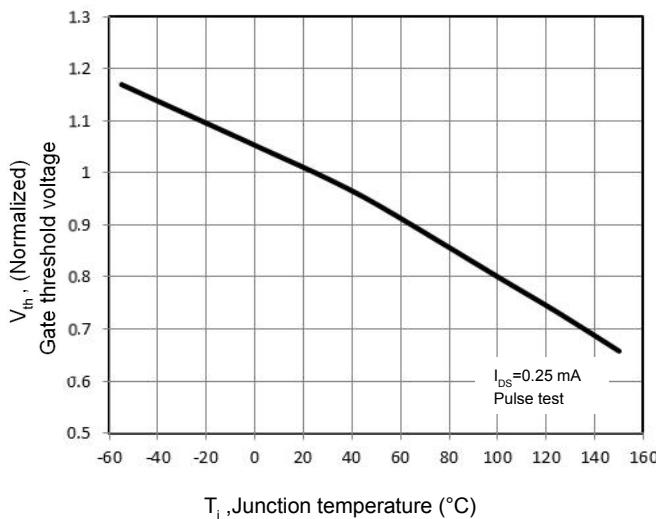


Figure 5. Breakdown Voltage vs. Temperature

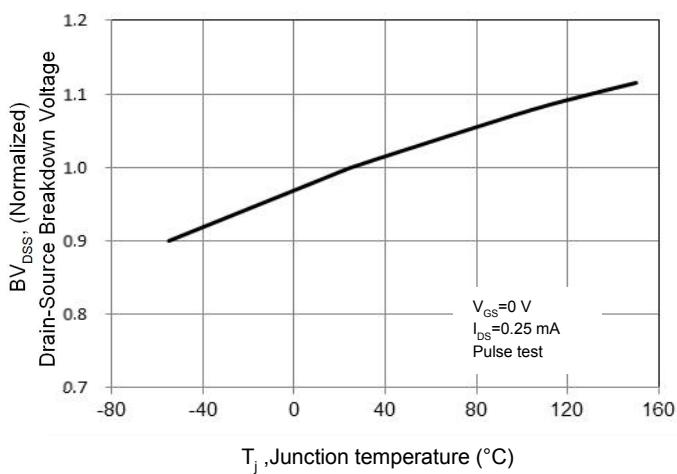


Figure 6. On-Resistance vs. Temperature

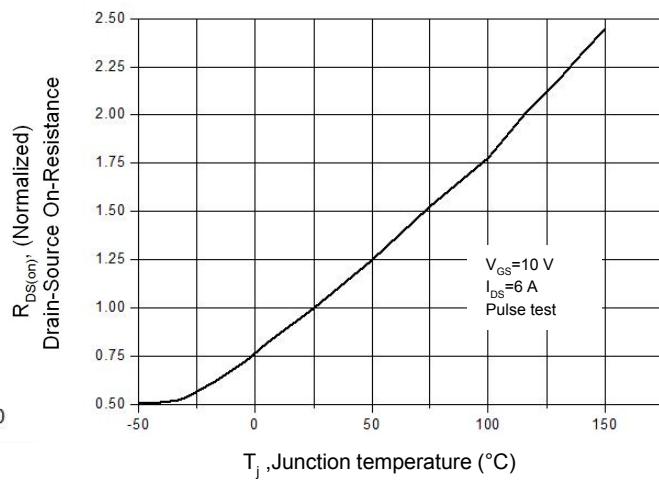


Figure 7. Capacitance Characteristics

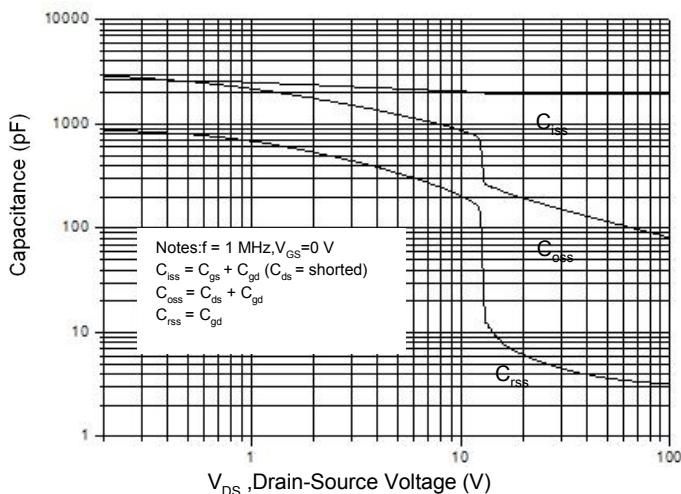


Figure 9. Maximum Safe Operating Area

TO-220F/TO-220F Narrow Pin

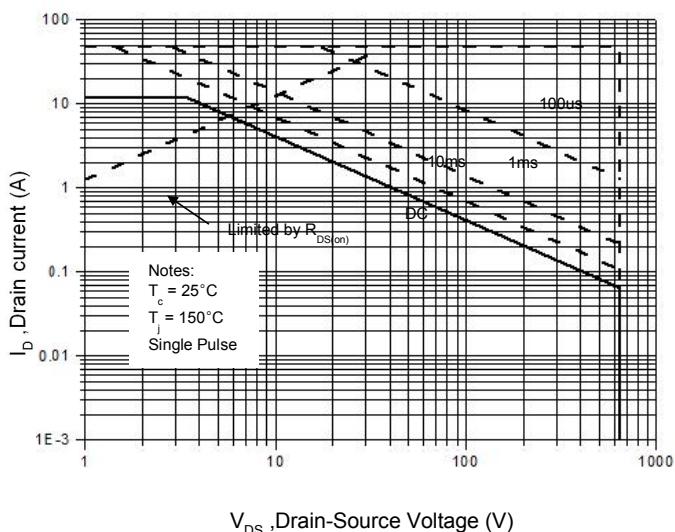


Figure 11. Power Dissipation vs. Temperature

TO-220F/TO-220F Narrow Pin

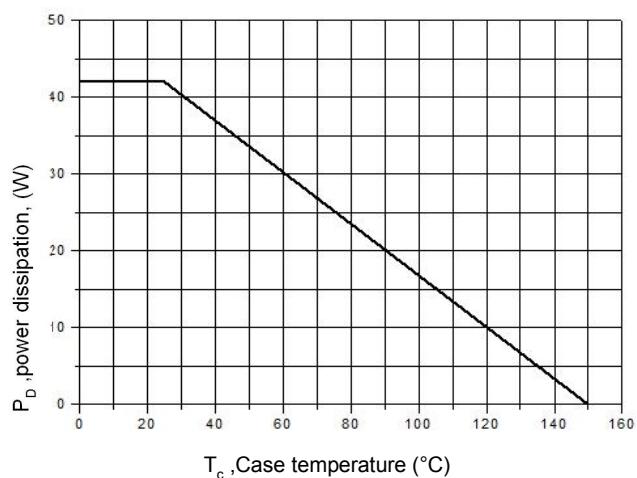


Figure 8. Gate Charge Characteristics

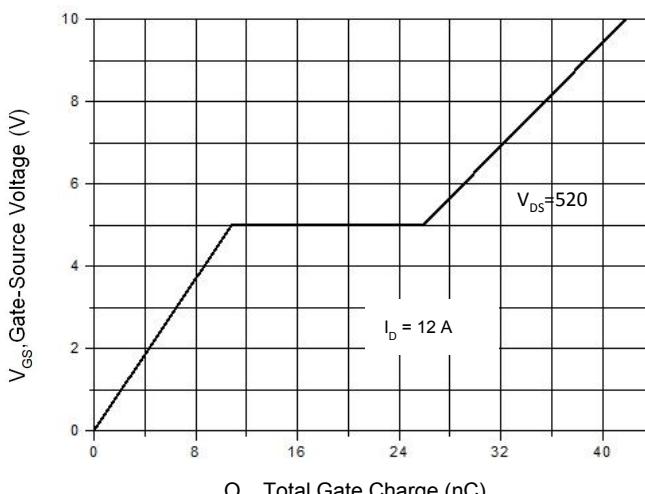


Figure 10. Maximum Safe Operating Area

TO-220/ TO-262/TO-263

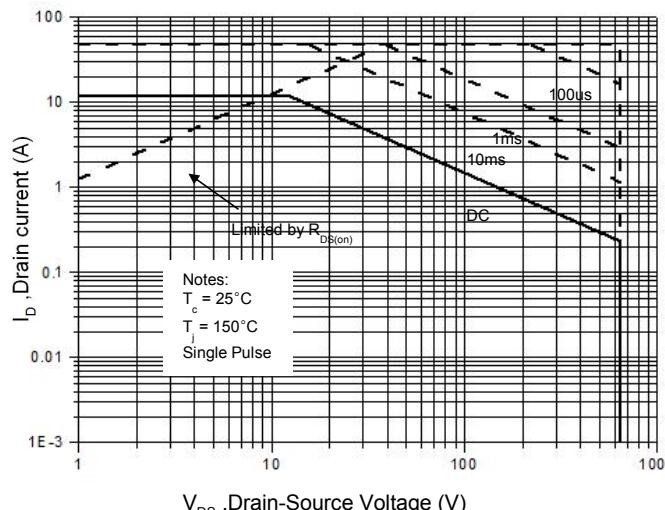


Figure 12. Power Dissipation vs. Temperature

TO-220/ TO-262/TO-263

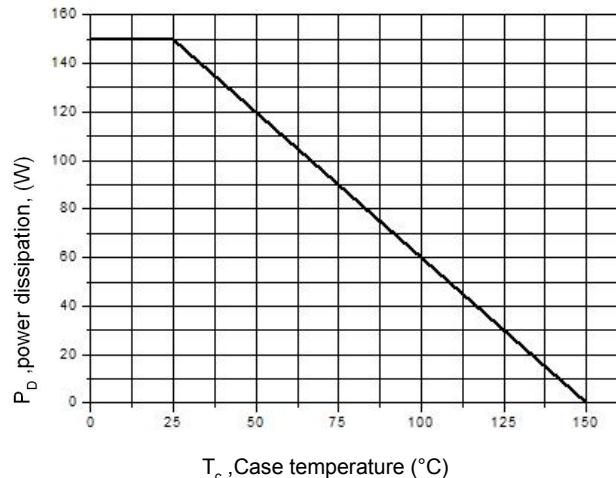


Figure 13. Continuous Drain Current vs. Temperature

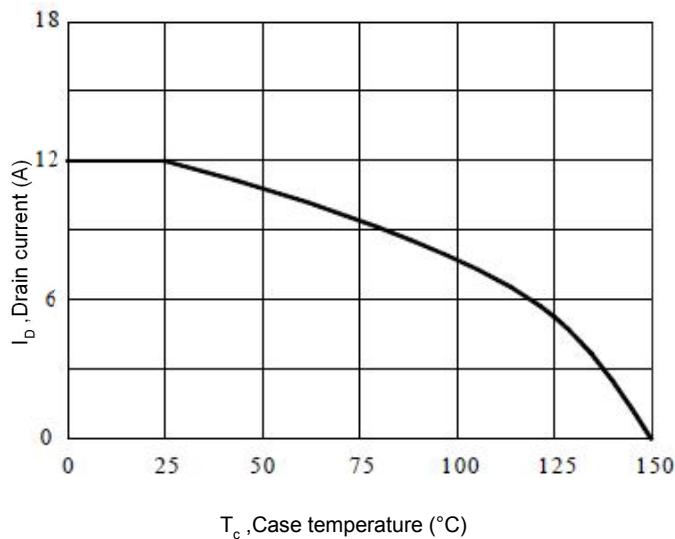


Figure 14. Body Diode Transfer Characteristics

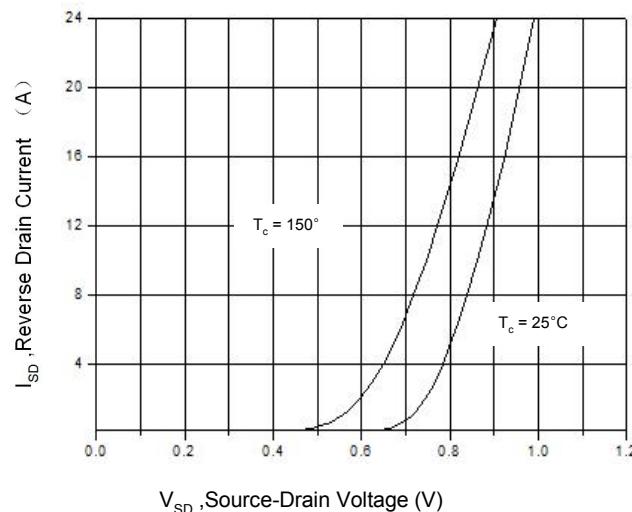


Figure 15 Transient Thermal Impedance, Junction to Case, TO-220F/TO-220F Narrow Pin

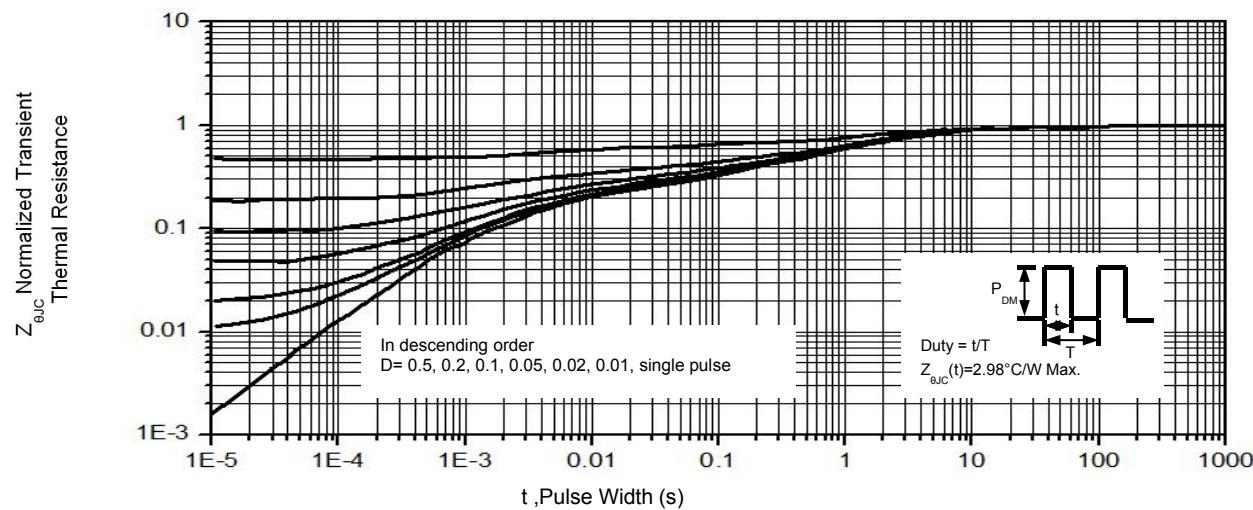
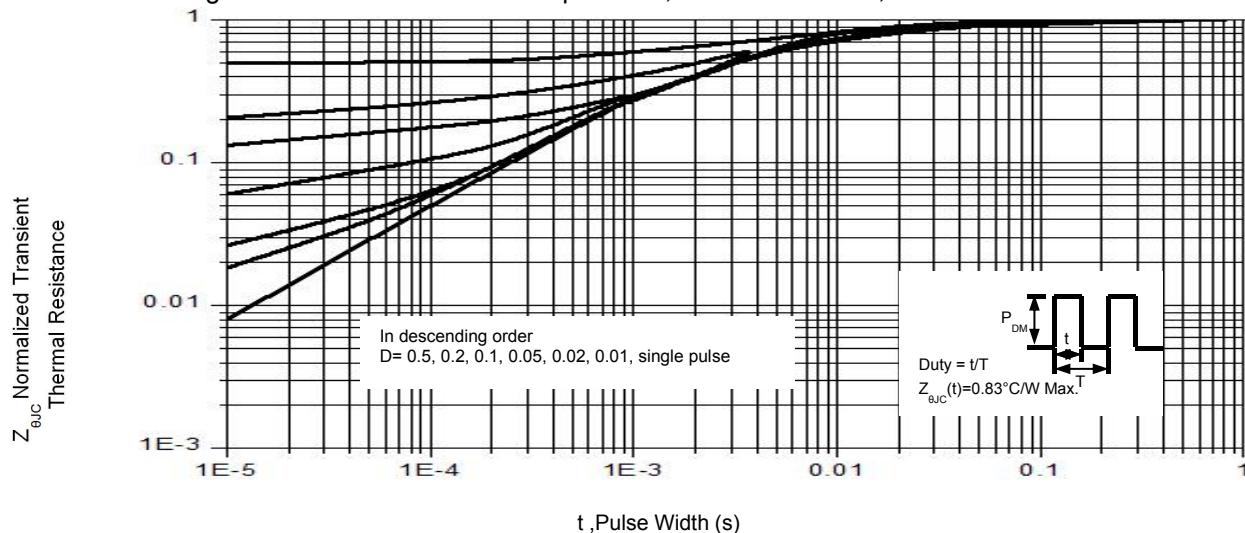
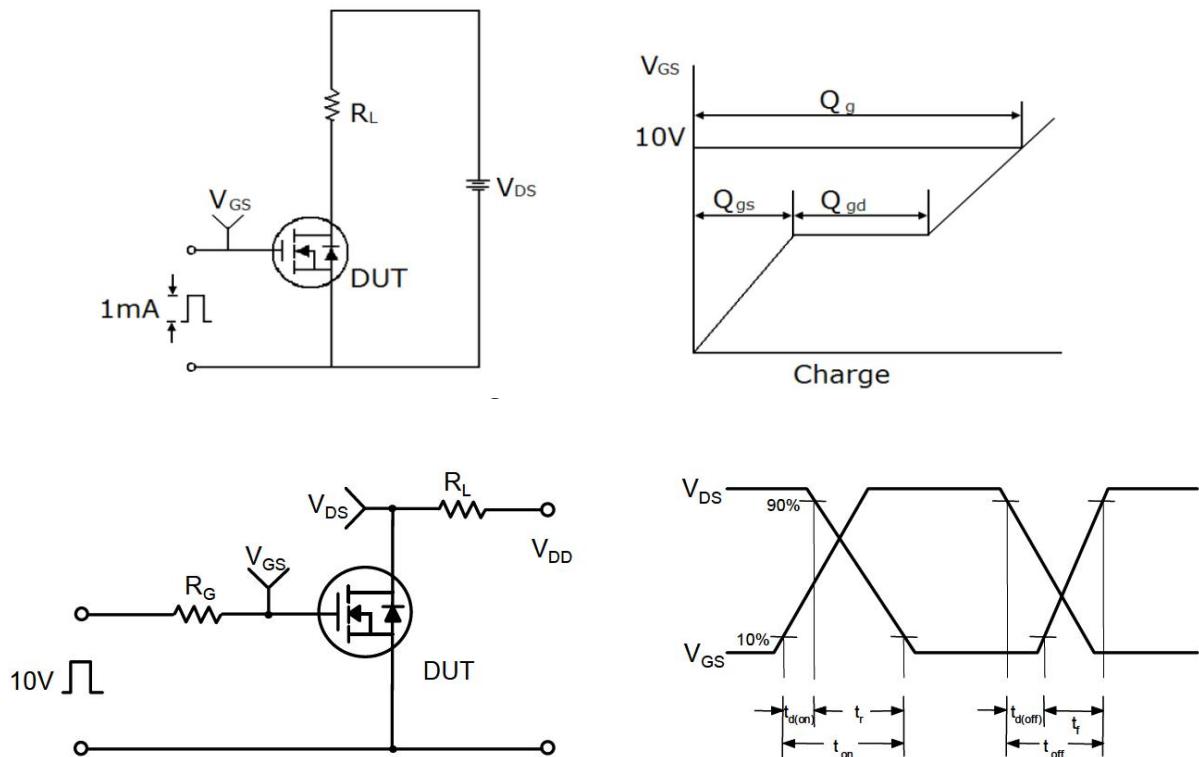


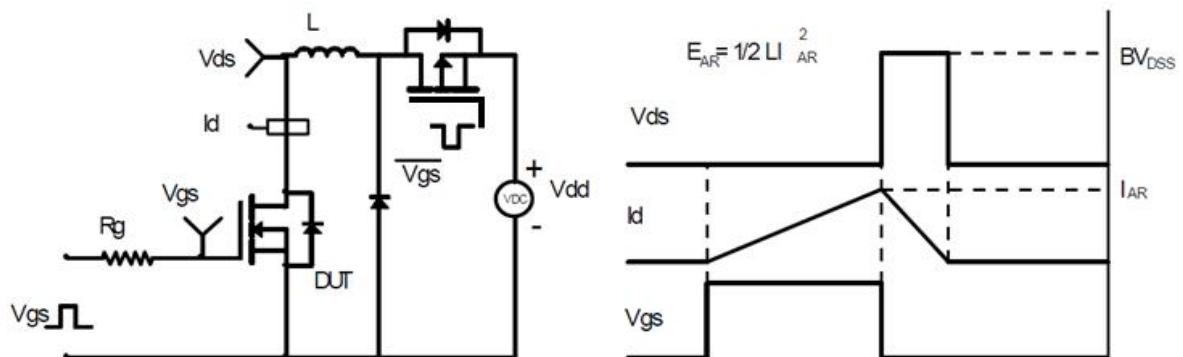
Figure 16. Transient Thermal Impedance, Junction to Case, TO-220/ TO-262/TO-263



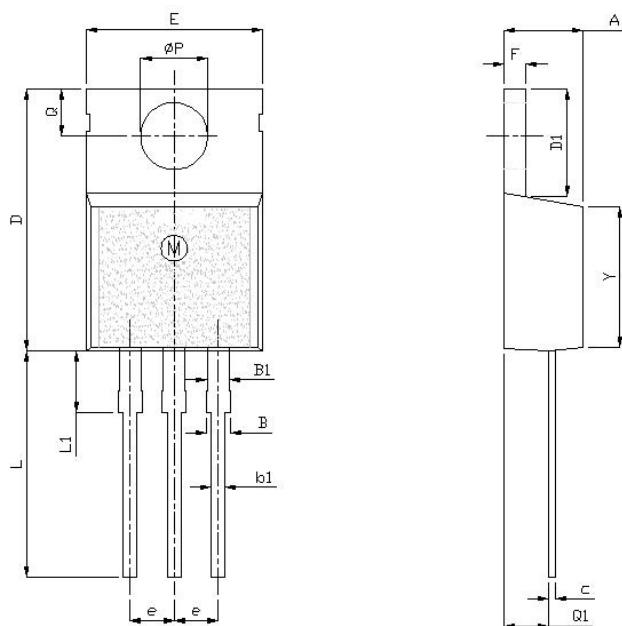
### Gate Charge Test Circuit & Waveform



### Unclamped Inductive Switching Test Circuit & Waveforms



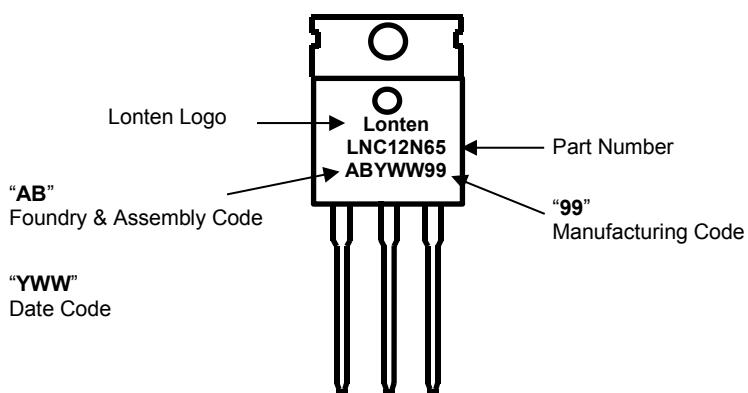
**Mechanical Dimensions for TO-220**



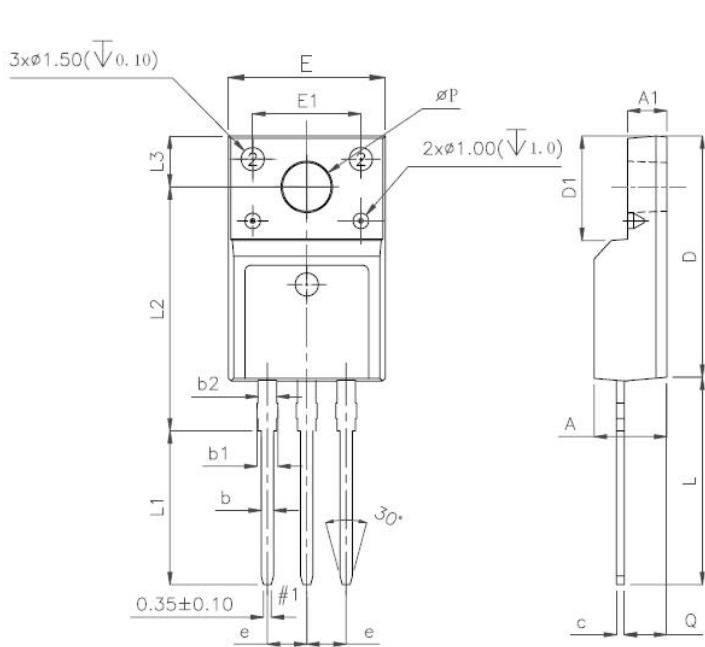
UNIT: mm

SYMBOL	MIN	NOM	MAX
A	4		4.8
B	1.2		1.4
B1	1		1.4
b1	0.75		0.95
c	0.4		0.55
D	15		16.5
D1	5.9		6.9
E	9.9		10.7
e	2.44	2.54	2.64
F	1.1		1.4
L	12.5		14.5
L1	3	3.5	4
ΦP	3.7	3.8	3.9
Q	2.5		3
Q1	2		2.9
Y	8.02	8.12	8.22

**TO-220 Part Marking Information**

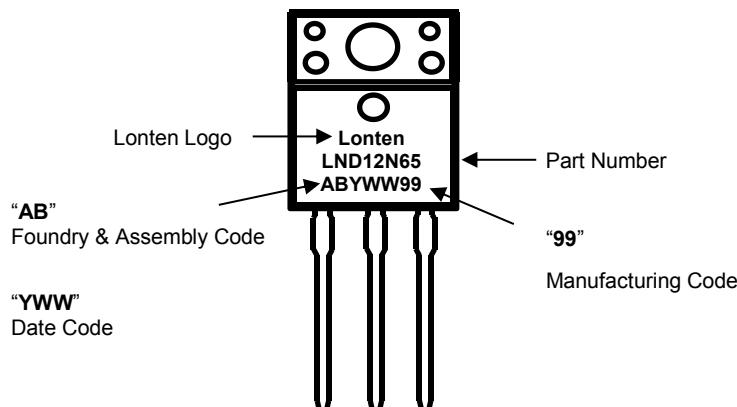


### Mechanical Dimensions for TO-220F

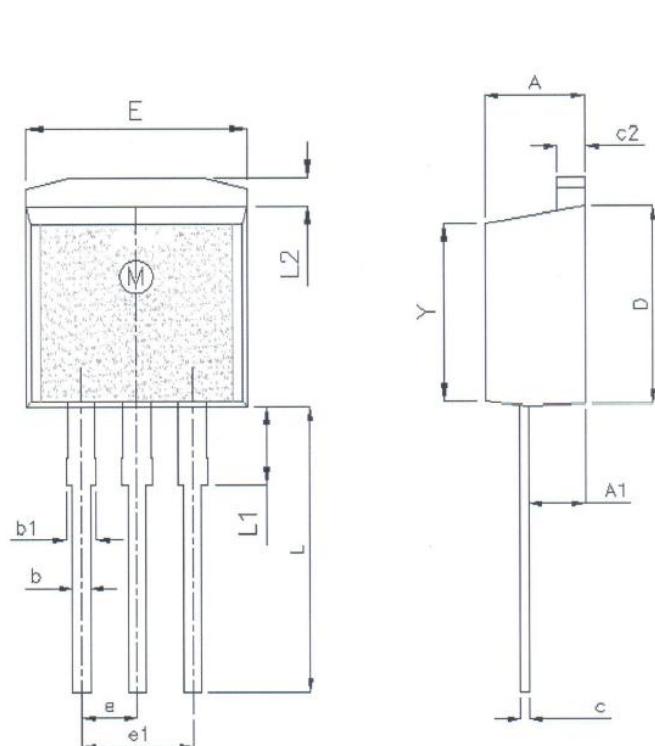


UNIT: mm			
SYMBOL	MIN	NOM	MAX
A	4.5		4.9
A1	2.3		2.9
b	0.65		0.9
b1	1.1		1.7
b2	1.2		1.4
c	0.35		0.65
D	14.5		16.5
D1	6.1		6.9
E	9.6		10.3
E1	6.5	7	7.5
e	2.44	2.54	2.64
L	12.5		14.3
L1	9.45		10.05
L2	15		16
L3	3.2		4.4
ΦP	3		3.3
Q	2.5		2.9

### TO-220F Part Marking Information

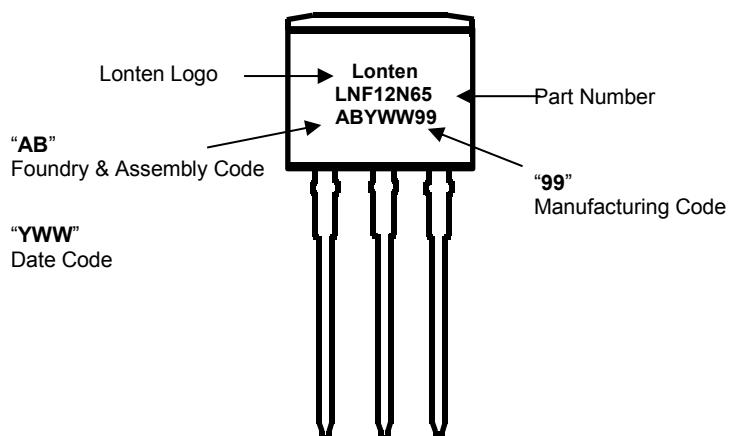


**Mechanical Dimensions for TO-262**

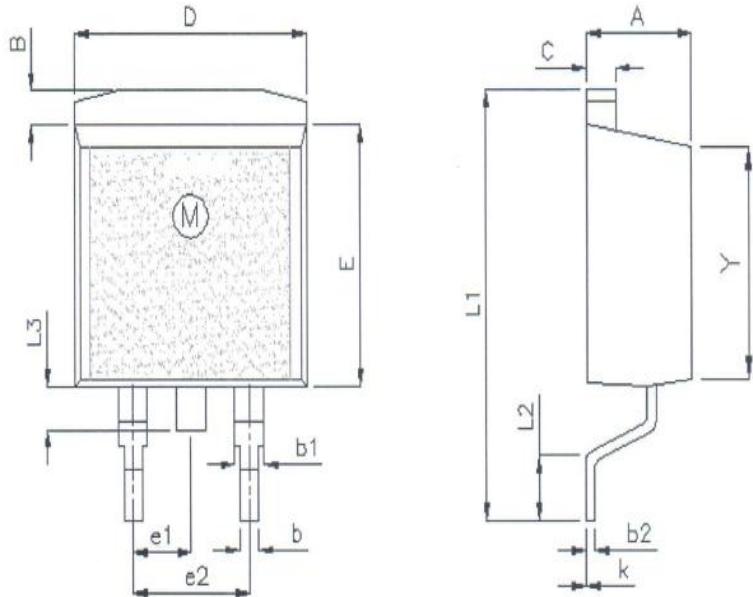


UNIT: mm			
SYMBOL	MIN	NOM	MAX
A	4.42		4.72
A1	2.40		2.80
b	0.76		0.86
b1	1.22		1.40
c	0.33		0.43
c2	1.22		1.35
D	8.99		9.29
e	2.44	2.54	2.64
e1	4.98		5.18
E	9.95		10.25
L	12.50		13.60
L1	3.30	3.50	3.80
L2	1.22		1.40
Y	8.02	8.12	8.22

**TO-262 Part Marking Information**

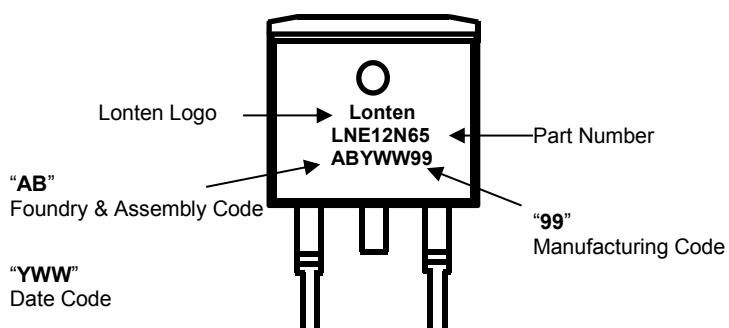


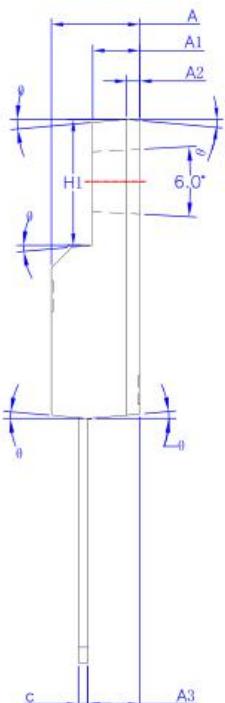
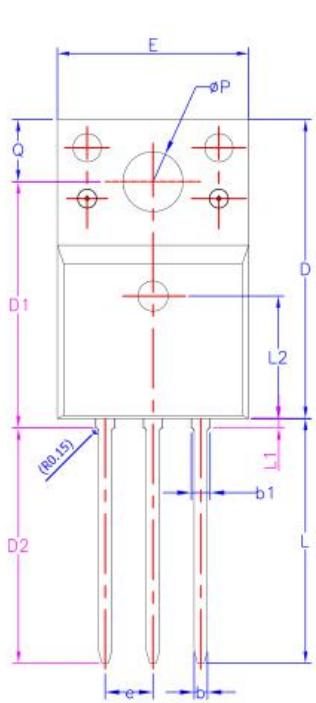
**Mechanical Dimensions for TO-263**



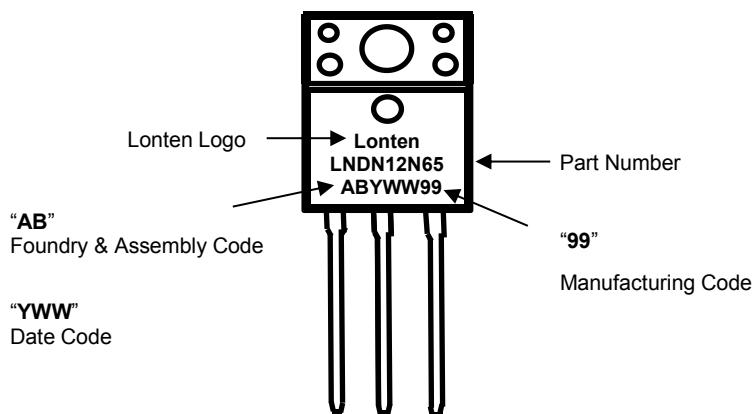
UNIT: mm			
SYMBOL	MIN	NOM	MAX
A	4.42		4.72
B	1.22		1.4
b	0.76		0.86
b1	1.22		1.4
b2	0.33		0.43
C	1.22		1.35
D	9.95		10.25
E	8.99		9.29
e1	2.44	2.54	2.64
e2	4.98		5.18
L1	14.7	15.1	15.5
L2	2	2.3	2.6
L3	1.5		2
K	-0.1		0.1
Y	8.02	8.12	8.22

**TO-263 Part Marking Information**



**Mechanical Dimensions for TO-220F Narrow Pin**


(UNITS:mm)			
SYMBOL	MIN	NOM	MAX
A	4.50	4.70	4.83
A1	2.34	2.54	2.74
A2	0.70	REF	
A3	2.56	2.76	2.93
b	0.60	—	0.80
b1	0.90	—	1.10
c	0.45	0.50	0.60
D	15.67	15.87	16.07
D1	12.87	13.07	13.27
D2	12.28	12.48	12.68
E	9.96	10.16	10.36
e	2.54	BSC	
H1	6.48	6.68	6.88
L	12.68	12.98	13.28
L1	—	—	0.85
L2	6.50	REF	
φP	3.08	3.18	3.28
Q	3.20	—	3.40
θ 1	1°	3°	5°

**TO-220F Narrow Pin Part Marking Information**


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